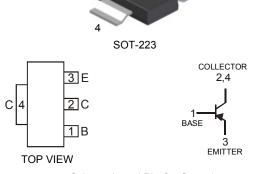




DZT591C PNP SURFACE MOUNT TRANSISTOR

Features

- Epitaxial Planar Die Construction
- Complementary NPN Type Available (DZT491)
- Ideally Suited for Automated Assembly Processes
- Ideal for Medium Power Switching or Amplification Applications
- Lead Free By Design/RoHS Compliant (Note 1)
- "Green" Device (Note 3)
- Mechanical Data
- Case: SOT-223
- Case Material: Molded Plastic, "Green" Molding Compound.
 UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020C
- Terminals: Finish Matte Tin annealed over Copper Leadframe (Lead Free Plating). Solderable per MIL-STD-202, Method 208
- Marking & Type Code Information: See Page 3
- Ordering Information: See Page 3
- Weight: 0.115 grams (approximate)



Schematic and Pin Configuration

3

Maximum Ratings $@T_A = 25^{\circ}C$ unless otherwise specified

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V _{CBO}	-80	V
Collector-Emitter Voltage	V _{CEO}	-60	V
Emitter-Base Voltage	V _{EBO}	-5	V
Collector Continuous Current (Note 3)	lc	-1	А
Peak Collector Current	I _{CM}	-2	А
Base Current	IB	-200	mA
Power Dissipation (Note 3)	Pd	1	W
Operating and Storage Temperature Range	T _j , T _{STG}	-55 to +150	°C

Electrical Characteristics @T_A = 25°C unless otherwise specified

Characteristic	Symbol	Min	Тур	Max	Unit	Test Conditions
OFF CHARACTERISTICS (Note 4)						·
Collector-Base Cutoff Current	I _{CBO}	_	_	-100	nA	$V_{CB} = -60V$
Emitter-Base Cutoff Current	I _{EBO}	_	_	-100	nA	$V_{EB} = -4V$
Collector-Emitter Cutoff Current	I _{CES}	_	_	-100	nA	$V_{CES} = -60V$
Collector-Base Breakdown Voltage	V _{(BR)CBO}	-80		_	V	I _C = 100μA
Collector-Emitter Breakdown Voltage	V _{(BR)CEO}	-60		_	V	I _C = 10mA
Emitter-Base Breakdown Voltage	V _{(BR)EBO}	-5		_	V	I _E = 100μA
ON CHARACTERISTICS (Note 4)						
Collector-Emitter Saturation Voltage	Variation			-0.3	V	I _C = -500mA, I _B = -50mA
	V _{CE(SAT)}	_	—	-0.6	V	I _C = -1A, I _B = -100mA
DC Current Gain		100		_	—	$V_{CE} = -5V, I_{C} = -1mA$
	h	100		300		V _{CE} = -5V, I _C = -500mA
	h _{FE}	80				V _{CE} = -5V, I _C = -1A
		15				$V_{CE} = -5V, I_{C} = -2A$
Base-Emitter Saturation Voltage	V _{BE(SAT)}	_		-1.2	V	I _C = -1A, I _B = -100mA
Base-Emitter Turn-On Voltage	V _{BE(on)}	_	_	-1	V	I _C = -1A, V _{CE} = -5V
SMALL SIGNAL CHARACTERISTICS						
Current Gain-Bandwidth Product	f _T	150		_	MHz	V _{CE} = -10V, I _C = -50mA, f = 100MHz
Output Capacitance	Cobo	_	13	_	pF	V_{CB} = -10V, f =1MHz

Notes: 1. No purposefully added lead.

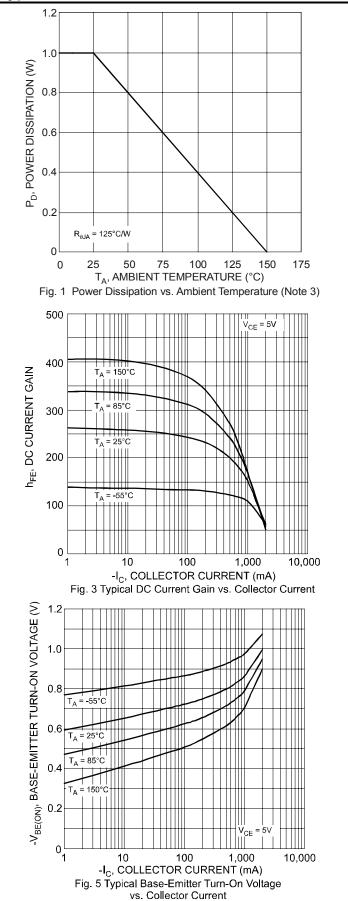
3. Device mounted on FR-4 PCB, pad layout as shown on page 4 or in Diodes Inc. suggested pad layout document AP02001, which can be found on our website at http://www.diodes.com/datasheets/ap02001.pdf.

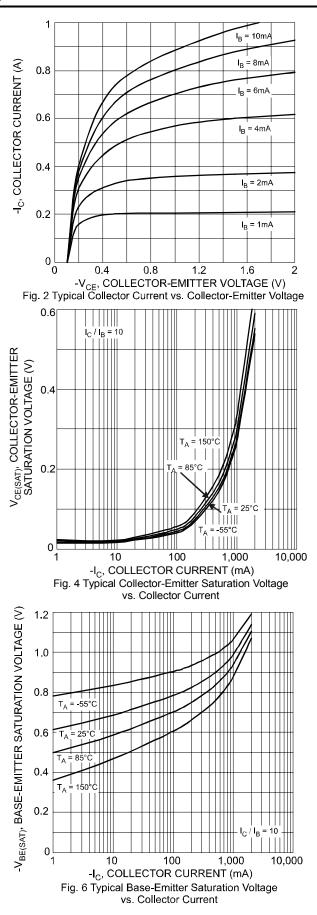
4. Measured under pulsed conditions. Pulse width = 300ms. Duty cycle ≤ 2%.

^{2.} Diodes Inc.'s "Green" policy can be found on our website at http://www.diodes.com/products/lead_free/index.php.



Typical Characteristics @T_A = 25°C unless otherwise specified

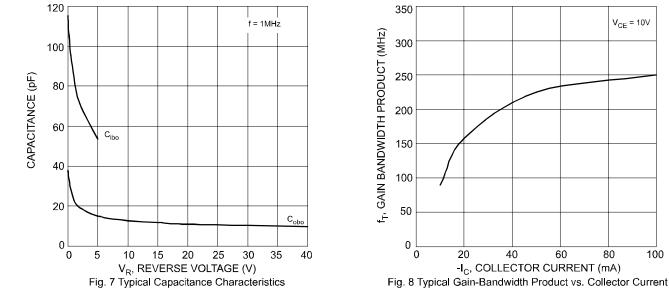




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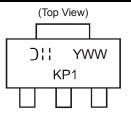


Ordering Information (Note 5)

Device	Packaging	Shipping
DZT591C-13	SOT-223	2500/Tape & Reel

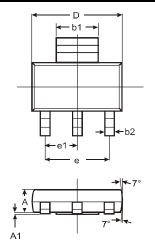
Notes: 5. For packaging details, go to our website at http://www.diodes.com/datasheets/ap02007.pdf.

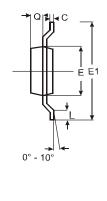
Marking Information



>!! = Manufacturer's code marking
KP1 = Product type marking code
YWW = Date code marking
Y = Last digit of year ex: 7 = 2007
WW = Week code 01 - 52

Package Outline Dimensions



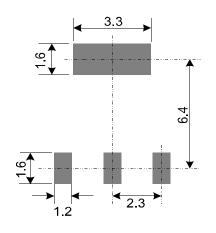


SOT-223					
Dim	Min	Max	Тур		
Α	1.55	1.65	1.60		
A1	0.010	0.15	0.05		
b1	2.90	3.10	3.00		
b2	0.60	0.80	0.70		
С	0.20	0.30	0.25		
D	6.45	6.55	6.50		
Е	3.45	3.55	3.50		
E1	6.90	7.10	7.00		
е	-	_	4.60		
e1		_	2.30		
L	0.85	1.05	0.95		
Q	0.84	0.94	0.89		
All Dimensions in mm					

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Suggested Pad Layout: (Based on IPC-SM-782)



(Unit: mm)

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